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TABLE OF CONTENTS

NEVER-ENDING CMOS INNOVATION: THE PAST, PRESENT, AND FUTURE PERSPECTIVES.....	3
<i>Toshiro Hiramoto</i>	
ADVANCED 3D WAFER LEVEL SYSTEM INTEGRATION TECHNOLOGY.....	9
<i>Kuo-Chung Yee, Doug C.H. Yu</i>	
3D HETEROGENEOUS INTEGRATION TECHNOLOGY FOR AL SYSTEM.....	11
<i>Mitsumasa Koyanagi</i>	
EXCURSION PREVENTION STRATEGY TO INCREASE CHIP PERFORMANCE BY PHOTOMASK TUNING.....	12
<i>Ofir Sharoni, Yael Sufrin, Avi Cohen, Rolf Seltmann, Aravind Narayana, Thomas Thamm</i>	
BIOELECTRONIC MEDICINE: TREATING DISEASES WITH MINIATURIZED BIOMIMETIC DEVICES.....	17
<i>Wentai Liu</i>	
SCALING OF SPLIT-GATE FLASH MEMORY FOR EMBEDDED CONTROLLERS AND MACHINE LEARNING APPLICATIONS.....	19
<i>Nhan Do, Steven Lemke, Hieu Tran, Vipin Tiwari, Mark Reiten</i>	
MEMORY FOR DATA-CENTRIC COMPUTING: A TECHNOLOGY PERSPECTIVE.....	21
<i>Yih Wang</i>	
TAOX RERAM AS A HIGHLY-RELIABLE EMBEDDED MEMORY AND ITS APPLICATION TO EDGE AL.....	22
<i>Ryutaro Yasuhara</i>	
THE PROMISE AND CHALLENGES OF QUANTUM COMPUTING.....	29
<i>Mark B. Ritter</i>	
3D STACKABLE VIA RRAM CELLS BY CU BEOL PROCESS IN FINFET CMOS TECHNOLOGIES.....	31
<i>Cheng-Jun Lin, Wang-Yi Lee, Chrong-Jung Lin, Ya-Chin King</i>	
IMPACT OF BOTTOM ELECTRODE INTEGRATION ON OXRAM ARRAYS VARIABILITY.....	33
<i>N.-P. Tran, J. Sandrini, A. Persico, J.-F. Nodin, T. Magis, R. Crochemore, N. Castellani, M.-C. Cyrille, G. Molas, E. Nowak</i>	
98% ENDURANCE ERROR REDUCTION BY HARD_VERIFY FOR 40NM TAO _x BASED RERAM.....	35
<i>Tsubasa Yonai, Hiroshi Kinoshita, Ryutaro Yasuhara, Ken Takeuchi</i>	
EMPIRICAL TUNNELING MODEL DESCRIBING THE RETENTION OF 2.5 MB HFO ₂ BASED RERAM.....	37
<i>S. Wiefels, U. Böttger, S. Menzel, D. J. Wouters, R. Waser</i>	
A STUDY OF READ VARIABILITY IN BACKFILL CONTACT RANDOM ACCESS MEMORY.....	39
<i>Fu-Cheng Chang, Yao-Hung Huang, Chrong-Jung Lin, Ya-Chin King</i>	

ACCELERATING COMMERCIALIZATION OF SIC POWER ELECTRONICS	43
<i>Victor Veliadis</i>	
IS GAN READY FOR COMMERCIALIZATION	45
<i>Yi-Jen Chan</i>	
NOVEL SJ-MOSFET WITH DISCONNECTED P-PILLARS FOR HIGH ROBUSTNESS	46
<i>Xin Tong, Zhaoming Yao, Qian Liu, Hong Yang, Siyang Liu, Wangran Wu, Weifeng Sun</i>	
GENERAL IZHIKEVICH DYNAMICS IN $PR_{0.7}CA_{0.3}MNO_3$ RRAM NEURON	48
<i>S. Lashkare, S. Chouhan, A. Bhat, U. Ganguly</i>	
SUBTHRESHOLD BEHAVIOR OF FERROELECTRIC JUNCTIONLESS TRANSISTOR	50
<i>Manish Gupta, Vita Pi-Ho Hu</i>	
OPTIMIZING READ VARIABILITY AND DESIGN GUIDELINES FOR ULTRA-THIN ($<5\text{NM}$) ANALOG BILAYER RRAM.....	52
<i>Jen-Chieh Liu, I-Ting Wang, Wendong Song, Weijie Wang, Hock Koon Lee, Aarthy Mani, Fei Li, Minghua Li, Zhixian Chen, Victor Yi-Qian Zhuo, Yao Zhu</i>	
DESIGN CONSIDERATIONS FOR CURRENT-ASSISTED PHOTONIC DEMODULATOR (CAPD) IN TIME-OF-FLIGHT CMOS IMAGE SENSOR	54
<i>Cristine Jin Estrada, Ying Xiao, Mansun Chan</i>	
LOW-ENVIRONMENTAL-INTERFERENCE & HIGHLY-SENSITIVE TMR BIOSENSOR FOR IN-VITRO DIAGNOSIS APPLICATION.....	56
<i>Yi-Ching Kuo, Hsin-Han Lee, Ding-Yeong Wang, Yao-Jen Chang, Shan-Yi Yang, Yu-Chen Hsin, I-Jung Wang, Guan-Long Chen, Yi-Hui Su, S.K. Ziaur Rahaman, Fang-Ming Chen, Jeng-Hua Wei, Pei-Jer Tzeng, Shyh-Shyuan Sheu, Wei-Chung Lo, Shih-Chieh Chang, Chih-I Wu</i>	
PROXIMITY EFFECT OF SELECTIVE CO ALD ON THE NANOSCALE	58
<i>M. Breeden, S. Wolf, A. Anurag, V. Wang, A. C. Kummel</i>	
CARRIER TRANSPORT IN MULTILAYER N-MOSE ₂ AND P-GERMANIUM HETEROJUNCTION BACK GATED FIELD EFFECT TRANSISTORS	60
<i>Wasi Uddin, Veerendra Dhyani, Gufran Ahmad, Samaresh Das</i>	
PERFORMANCE EVALUATION OF LOGIC CIRCUITS WITH 2D NEGATIVE- CAPACITANCE FETS CONSIDERING THE IMPACT OF SPACERS	62
<i>Chia-Chen Lin, Yi-Jui Wu, Wei-Xiang You, Pin Su</i>	
ADAPTIVE RANDOM NUMBER GENERATOR BASED ON RRAM INTRINSIC FLUCTUATION FOR REINFORCEMENT LEARNING.....	64
<i>Lin Bao, Zongwei Wang, Zhizhen Yu, Yichen Fang, Yuchao Yang, Yimao Cai, Ru Huang</i>	
A MULTI-PHYSICS TCAD FRAMEWORK FOR FAST AND ACCURATE SIMULATION OF STEEP-SLOPE SI-BASED COLD SOURCE FET	66
<i>Weizhuo Gan, Raphaël Prentki, Fei Liu, Jianhui Bu, Qingzhu Zhang, Huilong Zhu, Huaxiang Yin, Wenwu Wang, Tianchun Ye, Zhenhua Wu, Hong Guo</i>	
IMPACT OF SPACE CHARGE MODULATION ON SUPERJUNCTION-LDMOS.....	68
<i>Aakanksha Mishra, B. Sampath Kumar, Jhmanesh Somayaji, Mayank Shrivastava, Ankur Gupta</i>	

FORMATION OF FERROELECTRIC Y-DOPED HFO ₂ THROUGH ATOMIC LAYER DEPOSITION AND LOW TEMPERATURE POST ANNEALING	70
<i>K. Mizutani, Y.-W. Lin, T. Hoshii, H. Funakubo, H. Wakabayashi, K. Tsutsui, K. Kakushima</i>	
SIMULATION OF THE NANOSCALE INTERCONNECTS WITHIN A SPIN-RESOLVED ELECTRON TRANSPORT MODEL.....	72
<i>A. Useinov, H.-H. Lin, N. Useinov, L. Tagirov</i>	
MECHANISM OF DEGRADATION OF GE NMOSFET WITH CHANNEL ION IMPLANTATION AND ITS RECOVERY	74
<i>Bing-Yue Tsui, Yu-Chen Chang, Yi-Ju Chen</i>	
THERMAL PERFORMANCE ANALYSIS OF A PACKAGE USING NON-SIMULATION TECHNIQUE.....	76
<i>Heng-Chieh Chien, Mei-Jiau Huang, Zheng-Zhun Chen</i>	
SIMULATION AND DESIGN OF ULTRA-THIN-BODY FEFET NVMS CONSIDERING MINOR LOOP OPERATION.....	78
<i>Feng-Chi Wu, Wei-Xiang You, Pin Su</i>	
PLATINUM MEMBRANE ON TI/N-SI SUBSTRATE FOR DOPAMINE DETECTION	80
<i>Anisha Roy, Siddheswar Maikap, Pei-Jer Tzeng, Jiantai Timothy Qiu</i>	
SCALING LIMITATIONS OF LINE TFETS AT SUB-8-NM TECHNOLOGY NODE	82
<i>Narasimhulu Thoti, Yiming Li, Sekhar Reddy Kola</i>	
ANALYSIS OF NEGATIVE CAPACITANCE MOSFETS CHARACTERISTIC WITH SPACER	84
<i>Yu-Chun Lee, Sekhar Reddy Kola, Chieh-Yang Chen, Min-Hui Chuang, Yiming Li</i>	
ANALYSIS OF RACETRACK-COUPLED MACH ZEHNDER INTERFEROMETER FOR HIGH-SPEED COMMUNICATION.....	86
<i>Kai-Ning Ku, Po-Chih Chang, Chung-Chih Wang, Chen-Yu Lin, Chi-Hsiang Hsu, Ting-Hui Chen, Chien-Ying Huang, Sin-Jhu Wun, Chi-Sen Lee, Shang-Chun Chen, Ming-Chang Lee, Chien-Chung Lin, Chih-I Wu</i>	
GIANT ELECTRORESISTANCE SWITCHING OF TWO-DIMENSIONAL FERROELECTRIC α -IN ₂ SE ₃ ON P ⁺ -SI.....	88
<i>Ko-Chun Lee, José Ramón Durán Retamal, Fei Xue, Bin Cheng, Hao-Ling Tang, Ming-Hui Chiu, Wei-Jin Hu, Chih-I Wu, Mei-Hsin Chen, Lain-Jong Li, Chen-Hsin Lien, Jr-Hau He</i>	
A NOVEL 1T DRAM WITH SHELL/CORE DUAL-GATE ARCHITECTURE.....	90
<i>Md. Hasan Raza Ansari, Seongjae Cho</i>	
AB INITIO STUDY ON TUNING THE FERROELECTRICITY OF ORTHORHOMBIC HFO ₂	92
<i>Sheng-Ting Fan, Yun-Wen Chen, Pin-Shiang Chen, C. W. Liu</i>	
DFT MODELS OF NEGATIVE CAPACITANCE.....	94
<i>K. Chae, K. J. Cho, A. C. Kummel</i>	
ANALYSIS OF STEEP SS MECHANISM ON PN-BODY TIED SOI-FET WITH 65 NM THIN BOX FD-SOI.....	96
<i>Takayuki Mori, Jiro Ida, Keita Daimatsu</i>	
INFRARED RESPONSE OF STACKED GESN TRANSISTORS.....	100
<i>Hsiao-Hsuan Liu, Yu-Shiang Huang, Fang-Liang Lu, Hung-Yu Ye, C. W. Liu</i>	

IMPROVING INTERFACE STATE DENSITY OF TIN/HFO ₂ /IL GATE STACK ON SI _{0.5} GE _{0.5} BY OPTIMIZATION OF POST METALLIZATION ANNEALING AND OXYGEN PRESSURE.....	102
<i>Meng-Chien Lee, Wei-Li Lee, Cheng-Yu Yu, Hung-Ju Lin, Hsien-Ho Liu, Jun-Lin Zhang, Shin-Yuan Wang, Chen-Han Chou, Guang-Li Luo, Chao-Hsin Chien</i>	
FABRICATION AND DEVICE CHARACTERIZATION OF LARGE LINEAR DYNAMIC RANGE TUNNEL MAGNETORESISTANCE (TMR) SENSORS FOR SYSTEM APPLICATIONS.....	104
<i>Fang-Ming Chen, I-Jung Wang, Ding-Yeong Wang, Shan-Yi Yang, Yu-Chen Hsin, Yao-Jen Chang, Hsin-Han Lee, Guan-Long Chen, Yi-Ching Kuo, Yi-Hui Su, Sk. Ziaur Rahaman, Jeng- Hua Wei, Sih-Han Li, Shyh-Shyuan Sheu, Wei-Chung Lo, Shih-Chieh Chang, Chih-I Wu</i>	
600 MEV EFFECTIVE WORK FUNCTION TUNING BY SPUTTERED WN _x FILMS.....	106
<i>Chung-En Tsai, Chih-Hsiung Huang, Yu-Rui Chen, Chien-Te Tu, Yu-Shiang Huang, C. W. Liu</i>	
HIGH PERFORMANCE GAN HEMT AND GE FIN FET DEVICE REALIZING BY ATOMIC- LAYER DEFECT-FREE ETCHING WITH CHLORINE NEUTRAL BEAM.....	108
<i>Daisuke Otori, Niraj Man Shrestha, Yiming Li, Jenn-Hwan Tarng, Seiji Samukawa</i>	
DEPOSITION OF HIGH THERMAL CONDUCTIVITY ALN HEAT SPREADER FILMS.....	110
<i>Scott T. Ueda, Aaron McLeod, Michelle Chen, Chris Perez, Eric Pop, Dan Alvarez, Andrew C. Kummel</i>	
THE RESISTIVITY BOTTLENECK: THE SEARCH FOR NEW INTERCONNECT METALS.....	112
<i>Daniel Gall</i>	
ATOMICALLY-PRECISE DEPOSITION AND ETCHING OF METALS USING ELECTROCHEMISTRY - NEW PARADIGMS FOR METALLIZATION OF INTEGRATED CIRCUITS.....	114
<i>Rohan Akolkar</i>	
EPITAXIAL METALS FOR INTERCONNECTS BEYOND CU: RESISTIVITY, RELIABILITY	115
<i>Katayun Barmak, Kevin R. Coffey</i>	
NOVEL LOW K DIELECTRIC MATERIALS FOR NANO DEVICE INTERCONNECT TECHNOLOGY	117
<i>Son Van Nguyen, H. Shobha, T. Haigh, J. Chen, J. Lee, T. Nogami, E. Liniger, S. Cohen, C. K. Hu, H. Huang, Y. Yao, D. Canaperi, B. Peethala, T. Standaert, G. Bonilla</i>	
INFERENCE OF DEEP NEURAL NETWORKS WITH ANALOG MEMORY DEVICES	119
<i>Stefano Ambrogio, Pritish Narayanan, Hsin-Yu Tsai, Charles Mackin, Katherine Spoon, An Chen, Andrea Fasoli, Alexander Friz, Geoffrey W. Burr</i>	
POWER EFFICIENT HARDWARE ACCELERATORS FOR MACHINE LEARNING, COMBINATORIAL OPTIMIZATION, AND PATTERN MATCHING APPLICATIONS	121
<i>John Paul Strachan</i>	
NEUROMORPHIC COMPUTING SYSTEMS WITH EMERGING NONVOLATILE MEMORIES: A CIRCUITS AND SYSTEMS PERSPECTIVE.....	122
<i>Bonan Yan, Ziru Li, Brady Taylor, Hai Li, Yiran Chen</i>	
INVESTIGATION OF THE IMPACT OF INTERNAL METAL GATE – FROM MFM CAPACITORS TO TWO-LAYER-STACKED GAA POLY-SI NW FE-FETS	124
<i>Shen-Yang Lee, Han-Wei Chen, Chun-Chih Chung, Chiu-Huei Shen, Po-Yi Kuo, Yu-En Huang, Hsin-Yu Chen, Tien-Sheng Chao</i>	

COMPARATIVE EXPERIMENTAL STUDY OF JUNCTIONLESS AND INVERSION-MODE NANOWIRE TRANSISTORS FOR ANALOG APPLICATIONS.....	126
<i>D. Bosch, J.P. Colinge, J. Lugo, A. Tataridou, C. Theodorou, X. Garros, S. Barraud, J. Lacord, B. Sklenard, M. Casse, L. Brunet, P. Batude, C. Fenouillet-Béranger, D. Lattard, J. Cluzel, F. Allain, R. Nait Youcef, J.M. Hartmann, C. Vizioz, G. Audoit, F. Balestra, F. Andrieu</i>	
STACKED GE NANOSHEET GAAFETS FABRICATION AND STRAIN EFFECTS MEASUREMENT.....	128
<i>Chun-Lin Chu, Guang-Li Luo, Kehuey Wu, Shih-Hong Chen, Bo-Yuan Chen, Wen-Fa Wu, Wen-Kuan Yeh</i>	
QUATERNARY BARRIER ALINGAN/GAN-ON-SI HIGH ELECTRON MOBILITY TRANSISTOR WITH RECORD F_T - L_G PRODUCT OF 13.9 GHz- μ M.....	130
<i>Po-Tsung Tu, Indraneel Sanyal, Po-Chun Yeh, Heng-Yuan Lee, Li-Heng Lee, Chih-I Wu, Jen-Inn Chyi</i>	
DESIGN OF LOW VOLTAGE VERTICAL CHANNEL FACE-TUNNELING TFET USING GE/SIGE MATERIALS AND ITS SRAM CIRCUIT PERFORMANCE.....	132
<i>Akancha Gupta, C. K. Chiang, W. Y. Yang, E. R. Hsieh, Steve S. Chung</i>	
MANUFACTURING METHODOLOGY FOR CARBON NANOTUBE ELECTRONICS	134
<i>Christian Lau, Gage Hills, Mindy D. Bishop, Tathagata Srimani, Rebecca Ho, Pritpal Kanhaiya, Andrew Yu, Aya Amer, Minghan Chao, Max M. Shulaker</i>	
ENHANCING INTERCONNECT RELIABILITY AND PERFORMANCE BY 2D MATERIALS	136
<i>Zhihong Chen</i>	
SYNTHESIS OF HIGH-QUALITY 2D MATERIALS FOR ELECTRONIC APPLICATIONS	139
<i>Hiroki Ago</i>	
TWO-DIMENSIONAL LAYERED MATERIALS FOR ARTIFICIAL SYNAPSE	141
<i>Yen-Yu Chen, Chih-Pin Hsu, Pang-Shiuan Liu, Tuo-Hung Hou</i>	
MOS ₂ BASED CBRAM WITH MO/TI BARRIER LAYER FOR ARTIFICIAL SYNAPSE APPLICATION.....	143
<i>Asim Senapati, Sreekanth Ginnaram, Mrinmoy Dutta, Siddheswar Maikap</i>	
FUNDAMENTAL PROPERTIES OF FERROELECTRIC AND ANTI-FERROELECTRIC HAFNIUM ZIRCONIUM OXIDES: SCALING LIMIT, SWITCHING SPEED AND POLARIZATION DENSITY.....	145
<i>Peide Ye</i>	
HFO ₂ -BASED FERROELECTRIC FETS: PERFORMANCE OF SINGLE DEVICES AND MINI-ARRAYS.....	146
<i>Halid Mulaosmanovic, Franz Müller, Evelyn T. Breyer, Stefan Dünkel, Martin Trentzsch, Sven Beyer, Thomas Mikolajick, Stefan Slesazeck</i>	
FERROELECTRIC HFZRO ₂ FETS FOR EMERGING TECHNOLOGIES.....	148
<i>Min-Hung Lee</i>	
EMERGING FERROELECTRIC-HFO ₂ BASED DEVICE TECHNOLOGIES FOR ENERGY-EFFICIENT COMPUTING	149
<i>Masaharu Kobayashi</i>	

STOCHASTIC STT-MRAM SPIKING NEURON CIRCUIT	151
<i>Fu-Xiang Liang, Paritosh Sahu, Ming-Hung Wu, Jeng-Hua Wei, Shyh-Shyuan Sheu, Tuo-Hung Hou</i>	
MRAM ACCELERATION CORE FOR VECTOR MATRIX MULTIPLICATION AND XNOR-BINARIZED NEURAL NETWORK INFERENCE.....	153
<i>Shifan Gao, Bing Chen, Yiming Qu, Yi Zhao</i>	
LOW TEMPERATURE HIGH VOLTAGE ANALOG DEVICES IN A 3D SEQUENTIAL INTEGRATION	155
<i>C. Cavalcante, X. Garros, P. Batude, A. Tataridou, J. Lacord, M. Casse, C. Theodorou, T. Karatsori, R. Gassilloud, C. Fenouillet-Beranger, L. Brunet, O. Rozeau, N. Rambal, F. Gaillard, F. Ponthenier, F. Allain, G. Romano, G. Ghibaudo, J-P. Colinge, M. Vinet, F. Andrieu</i>	
GRADUAL RESISTIVE SWITCHING IN ELECTRON BEAM IRRADIATED RES ₂ TRANSISTOR AND ITS APPLICATION AS ELECTRONIC SYNAPSE	157
<i>Sifan Li, Bochang Li, Xuwei Feng, Li Chen, Yesheng Li, Li Huang, Xiao Gong, Xuanyao Fong, Kah-Wee Ang</i>	

Author Index